

## Hall IC Fan Motor Driver

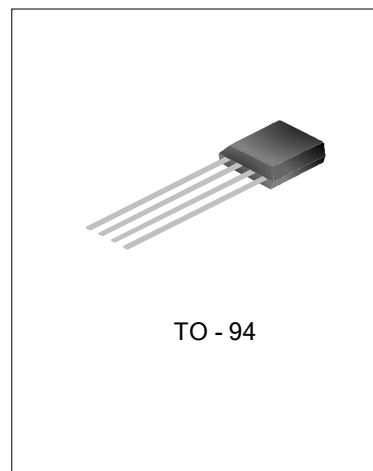
### DESCRIPTION

SD1579 is a one-chip, two phase Hall IC fan driver use the advanced BICDMOS process. Power output stage using LDMOS transistors, with low  $R_{ds(on)}$ , low power dissipation and capable of withstanding high output drive current.

The driver of the motor circuit built-in Locked-rotor protection circuit, with automatic restart function. Built-in voltage regulator circuit for the Hall sensor and amplifier circuit to provide internal power supply;

The dynamic compensation circuit capable of providing good consistency and very small magnetic shift of the window over the whole temperature range,.

Built-in Zener output as the output protection management and in the supply-side built-in reverse protection diodes, which can effectively prevent damage when the power supply circuit is reverse.



### FEATURES

- \* Built-in lock protection circuit;
- \* Built-in Auto restart circuit;
- \* Built-in Hall sensor with high stability of the dynamic compensation circuit;
- \* Built-in Hall amplifier with hysteresis;
- \* Built-in Zener Diodes protect outputs circuit;
- \* Built-in Voltage Regulator circuit.
- \* Built-in Reverse-voltage protection diode
- \* Hall magnetic window, consistency and temperature stability;
- \* Wide operating voltage range, small quiescent current;
- \* Low  $R_{ds(on)}$ , high drive current capability;

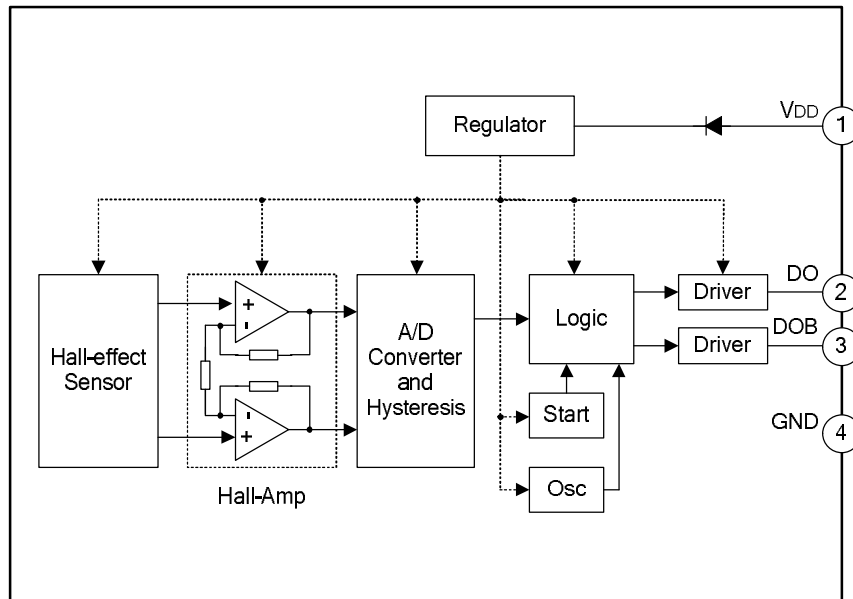
### APPLICATIONS

- \* Dual coils brush-less DC fan;
- \* Dual coils brush-less DC motor.

### ORDERING INFORMATION

Part No.	Package	Marking	Material	Package Type
SD1579	TO-94	1579	Pb free	Bulk

## BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Characteristics	Symbol	Ratings	Unit
Vcc Maximum Supply Voltage	VCC max	30	V
Maximum Output Current (Fault)	I <sub>out(AVE)</sub>	500	mA
	I <sub>out(PEAK)</sub>	700	mA
Power Dissipation	P <sub>d</sub>	550	mW
Operating Temperature Range	T <sub>amb</sub>	-40 ~ 125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~ 150	°C
Maximum Junction Temperature	T <sub>j</sub>	150	°C

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

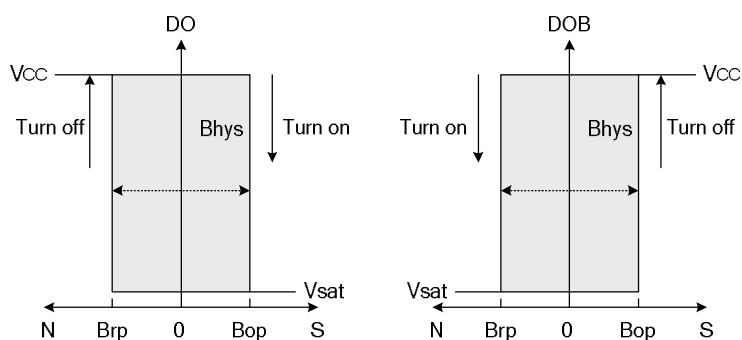
## ELECTRICAL CHARACTERISTICS (Unless specified particularly T<sub>amb</sub>=25°C, VCC=12V)

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Supply Voltage	VCC	Operating	~	12	28*	V
Supply Current	ICC	Operating	~	2.0	4.0	mA
Output Saturation voltage	V <sub>DSS</sub>	I <sub>out</sub> =300 mA	~	210	300	mV
Output Saturation voltage	V <sub>DSS</sub>	I <sub>out</sub> =500 mA	~	350	500	mV
Thermal Resistance	R <sub>th</sub>	Operating		227		°C/W
Locked-Rotor Period	t <sub>on</sub>			0.5		S
Locked-Rotor Period	t <sub>off</sub>			3		S
Output Zener-breakdown Voltage	V <sub>Z</sub>		35	42	60	V

\*Note: Please used in power dissipation limitation for all coil with different efficiency.

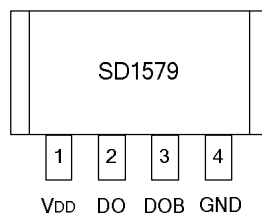
**MAGNETIC CHARACTERISTICS** (Unless specified particularly  $T_{amb}=25^{\circ}\text{C}$ ,  $V_{CC}=12\text{V}$ ,  $1\text{mT}=10\text{Gauss}$ )

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Operate Point	Bop	Operating	10	30	60	GS
Release Point	BRP	Operating	-60	-30	-10	GS
Hysteresis	BHYS	Operating	~	60	~	GS



When flux B is over operation point Bop, DO is on and output low voltage, DOB is off and output high voltage. Every output is locking until the flux B is less than release point Brp, then DO and DOB switch the states.

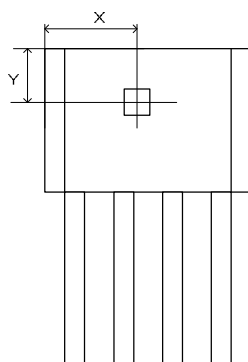
**PIN CONFIGURATION**



**PIN DESCRIPTION**

Pin No.	Pin Name	I/O	Description
1	VDD	--	Power supply
2	DO	O	Driver Output pin
3	DOB	O	Driver Output pin
4	GND	--	Ground

**HALL SENSOR LOCATION**



	Value	Unit
X	2.3	mm
Y	1.09	mm

## FUNCTION DESCRIPTION

This IC detects the rotation of the motor by hall signal, and adjusts lock detection ON time ( $T_{ON}$ ) = 0.5S and lock detection OFF time ( $T_{OFF}$ ) = 3.0S by internal counter. The time ( $T_{NO}$ ,  $T_{OFF}$ ) sequence is shown below.

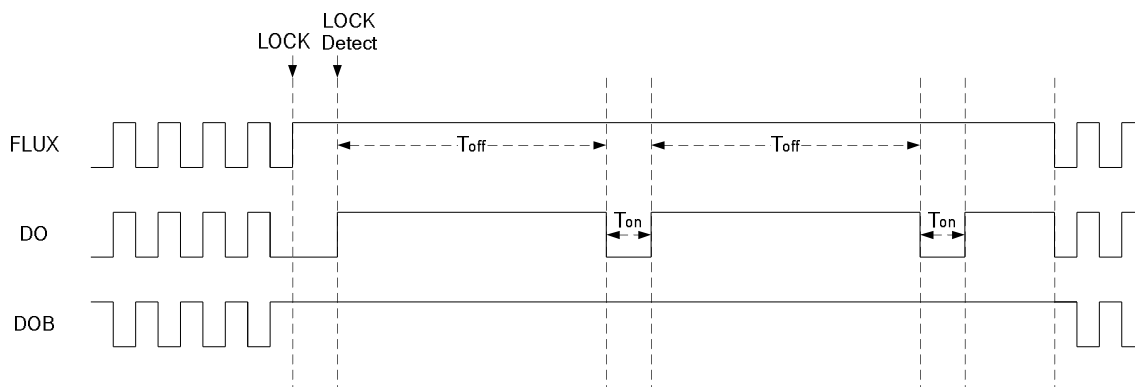
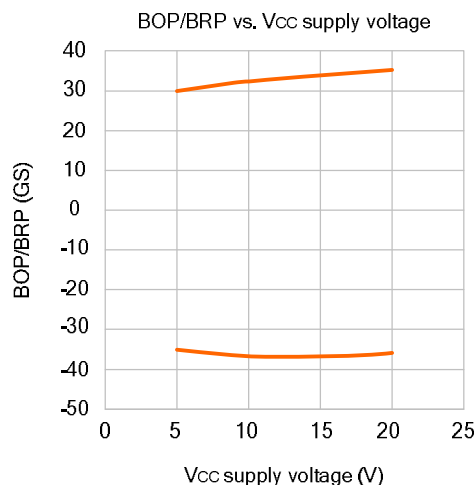
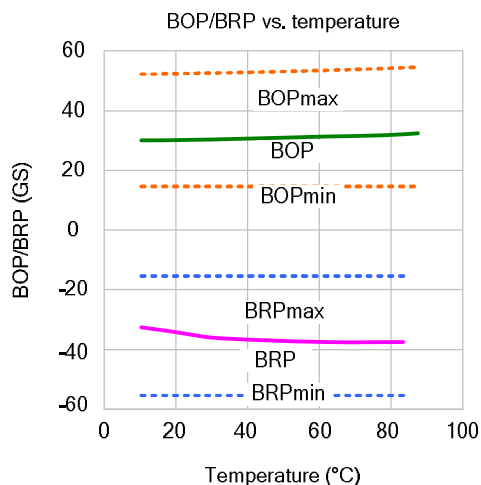
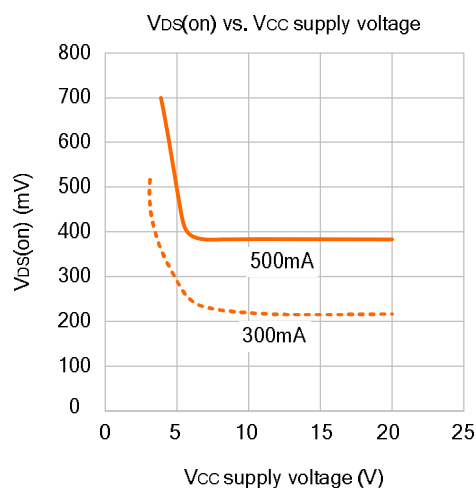
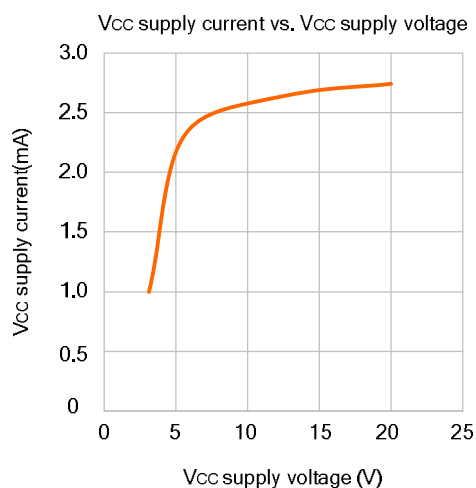
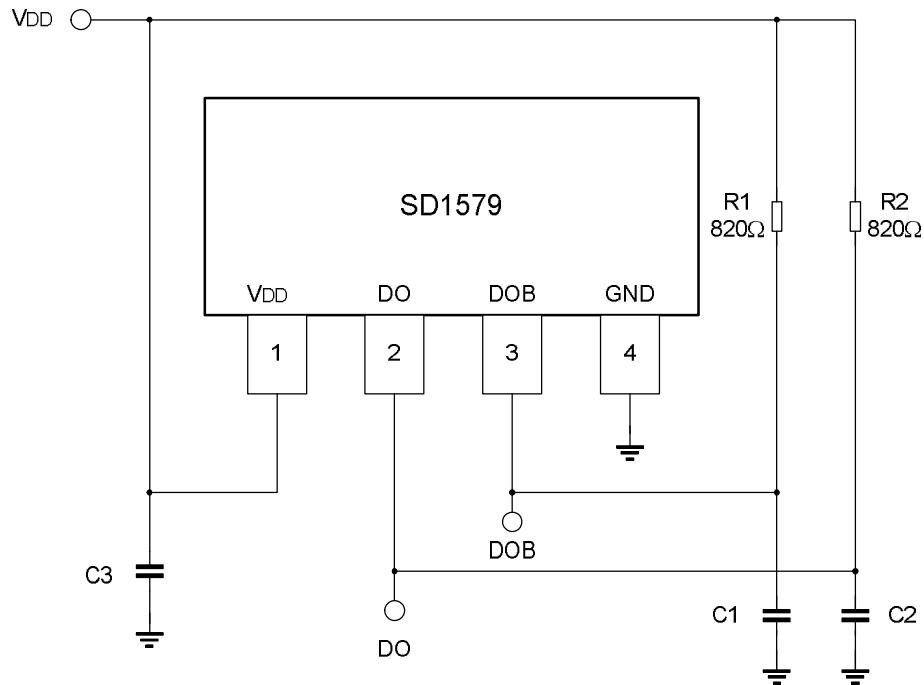


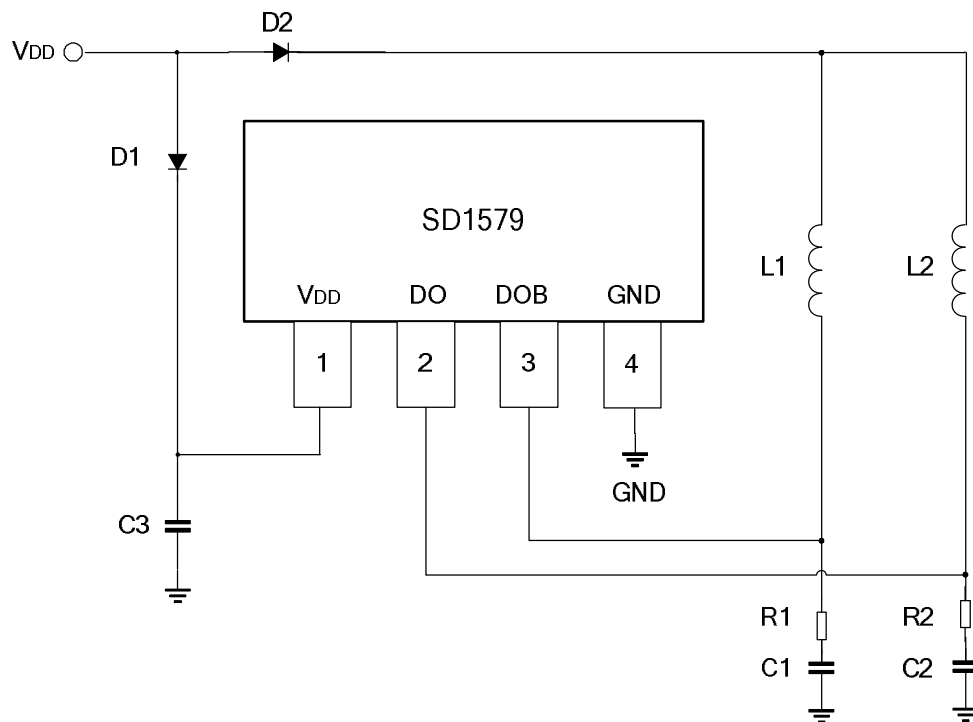
Fig 1. Lock Protection and Automatic Restart Waveform



## TEST CIRCUIT



## TYPICAL APPLICATION CIRCUIT



## APPLICATION INFORMATION

1. Back electromotive force causes regenerated current to VDD line, therefore take a measure such as placing a capacitor between power supply and GND for routing regenerated current; In order to reduce the output DO and DOB side effects of induced electromotive force, need to increase a resistance-capacitance network at the output; in a typical application circuit diagram, R1 and R2 is typically 56 ohms; C1, C2 and C3 is typically 2.2uF; The value of R and C must match the actual coil;
2. Figure 2 is the normal working state, the current compose  $I_{CC}$  and  $I_{load}$ , power dissipation  $PC = V_{DD} * I_{CC} + V_o * I_{load}$ , Where  $V_o$  is the output voltage when DO or DOB turn on; It is need to be careful not to exceed its maximum power dissipation value dule to change of power supply voltage  $V_{DD}$  and the coil current  $I_{load}$ .
3. SD1579 has built-in reverse protection diodes, so D1 is no need; If you increase the D1 can better protect the chips, as shown in Figure 3; it should be noted that care should to taken to the two coils current when power voltage reversed, if  $2 * V_o * I_{load} > IC's \text{ power consumption}$ , it may cause damage to IC;

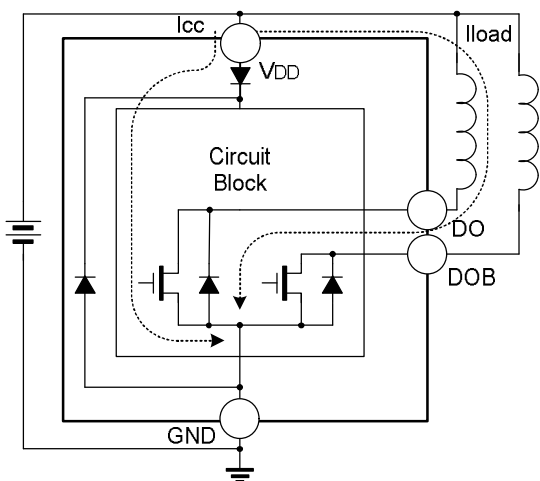


Fig.2 Normal working state

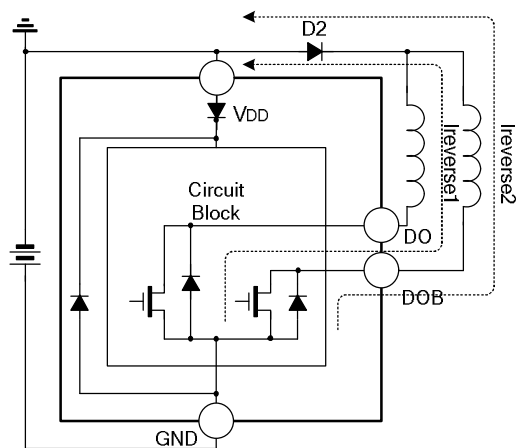


Fig.3 Reverse voltage state

4. Add a diode to coils can better protect the chip and the fans at reverse voltage state, as shown in Figure 4;

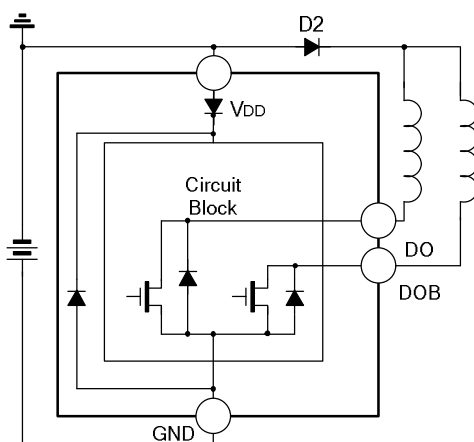
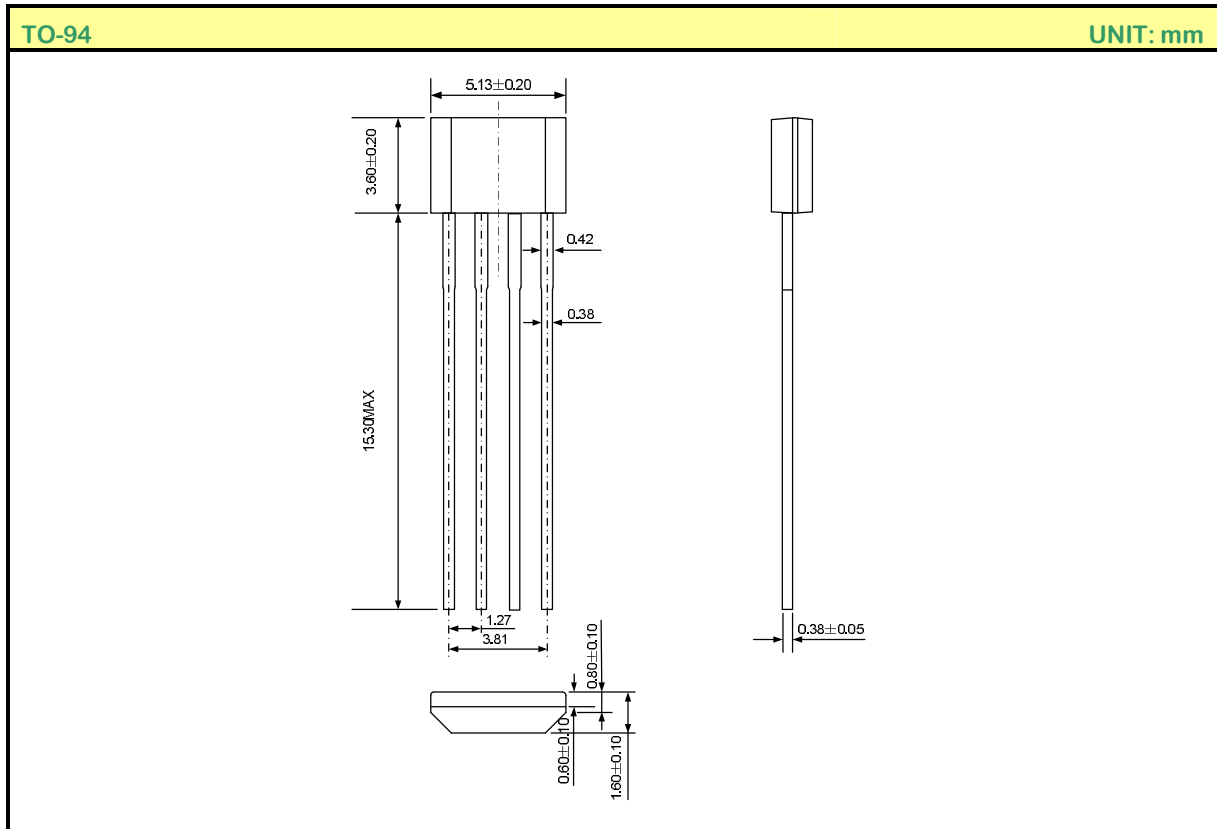


Figure 4 Add a diode to coils

## PACKAGE OUTLINE



### MOS DEVICES OPERATE NOTES:

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the MOS electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed in antistatic/conductive containers for transportation.

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